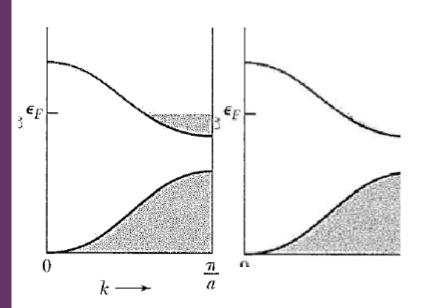
FoP 3B Part II

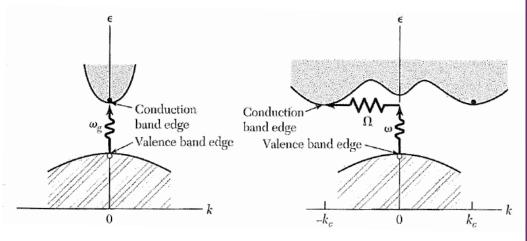
Dr Budhika Mendis (b.g.mendis@durham.ac.uk) Room 151

Lecture 2: Electrons and holes



Summary of Lecture 1



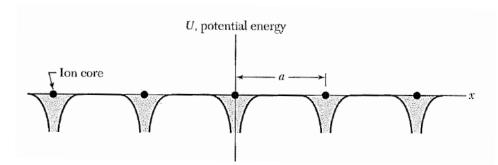


Direct vs indirect band gaps

Metals vs semiconductors

Durham

University



$$V = rac{1}{\hbar} rac{dE}{dk}$$

$$m^* = \hbar^2 / \frac{d^2E}{dk^2}$$

Aim of today's lecture

Q: How does a material conduct electricity?

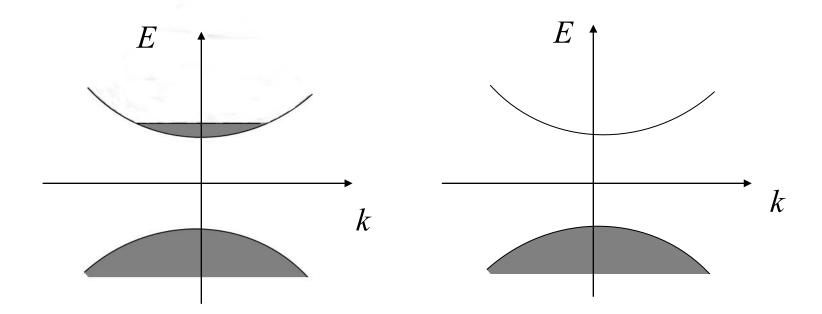
A: Electrons (nearly empty band) and holes (nearly full band)

Key concepts:

- -Conduction in a completely full band
- -Conduction in a nearly empty band (electrons)
- -Conduction in a nearly full band: concept of holes



Bands at zero electric field



Metal (partially full band)

Semiconductor (full band)

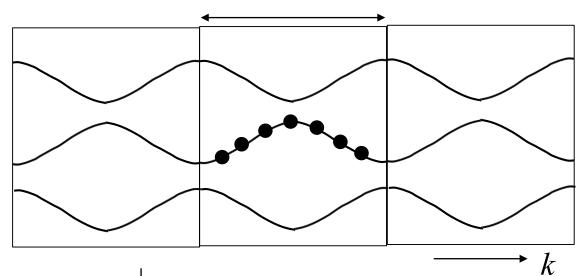
From symmetry:

- (i) $\sum \mathbf{k} = 0$ (no net crystal momentum)
- (ii) $\sum \mathbf{v} = 0$ (no net current)



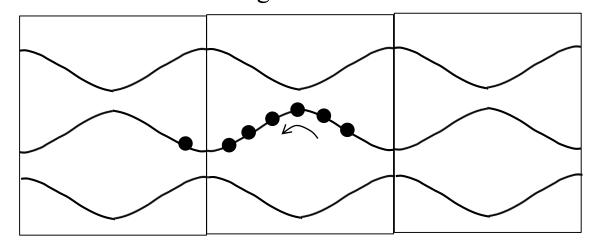
Conduction in a full band



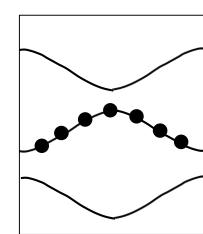


- Filled bands do not conduct electricity.
- Reason why semiconductors are insulating at 0K.

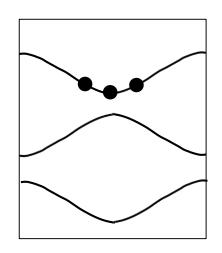
Electric field applied in +k direction and using $\mathbf{F} = \hbar d\mathbf{k}/dt$



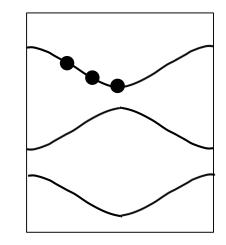
Reduced zone scheme



Conduction in a nearly empty band (electrons)

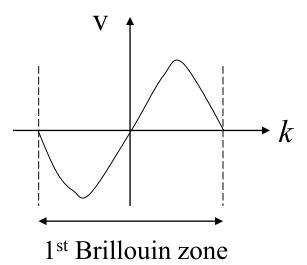


Apply electric field in +k direction



 $-\sum \mathbf{k}$, $\sum \mathbf{v} \neq 0$

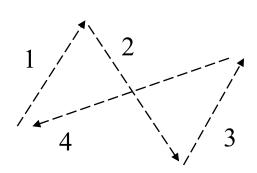
-instantaneous current in field direction



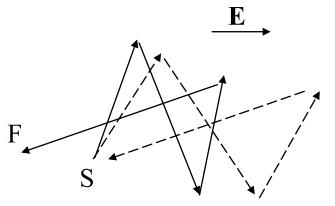
- -The *time averaged* velocity of an electron is however zero.
- -This implies that a *perfect* crystal with nearly empty band does not carry a current for any appreciable time!



Scattering in real materials (I)



Electron trajectory (no electric field)



Electron trajectory with electric field (dashed lines- zero electric field)

Electron acquires a net *drift* velocity \mathbf{v}_d given by:

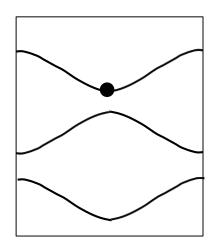
$$\mathbf{v}_d = -\mu \mathbf{E}$$

where μ is the mobility*.

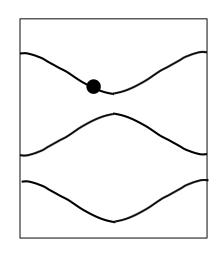


* See supplementary notes for a derivation and Hall measurement technique (non-examinable).

Scattering in real materials (II)

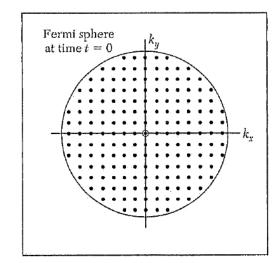


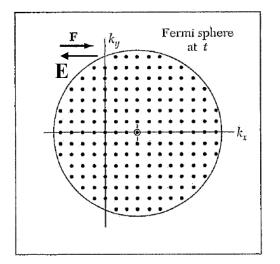
Apply electric field in +k direction



Electron at bottom of conduction band before applying electric field

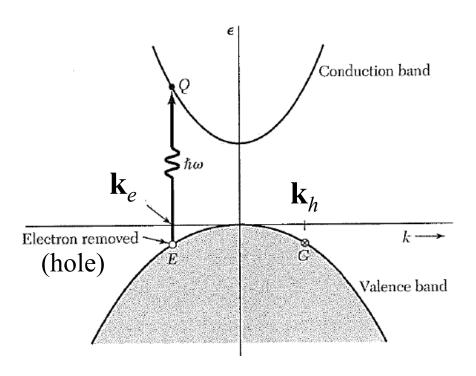
Time averaged state of electron in an electric field (scattering included)







Conduction in a nearly full band (holes)- I

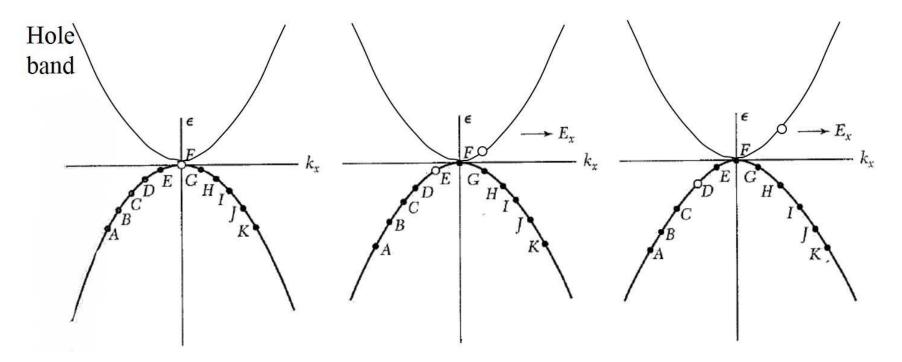


Semiconductors: photon/thermal excitation of valence electron into conduction band

- For a full band: $\sum \mathbf{k} = 0$
- After photon/thermal excitation: $\sum \mathbf{k} = -\mathbf{k}_e = \mathbf{k}_h$ (**k** of hole opposite to that of excited electron)



Conduction in a nearly full band (holes)- II



- Conduction of valence electrons equivalent to positively charged hole in hole band
- From the symmetry of valence and hole bands:

$$\mathbf{k}_h = -\mathbf{k}_e \, (\mathbf{k} \, \text{vector})$$
 $\mathbf{\epsilon}_h = -\mathbf{\epsilon}_e \, (\text{energy})$
 $\mathbf{v}_h = \mathbf{v}_e \, (\text{velocity})$
 $m_h^* = -m_e^* \, (\text{effective mass})$